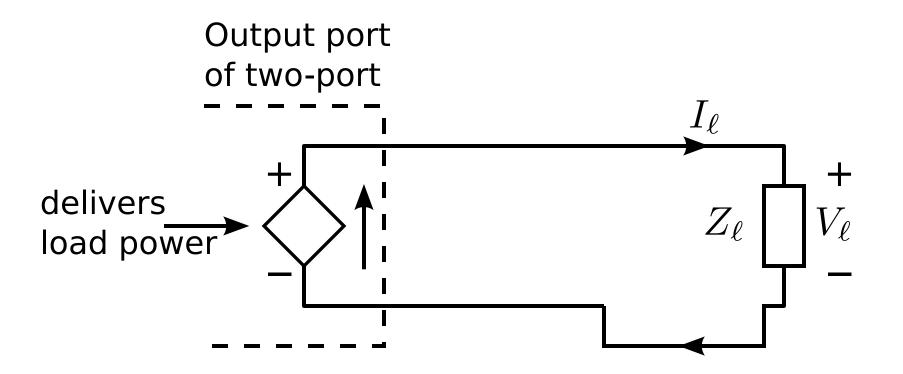
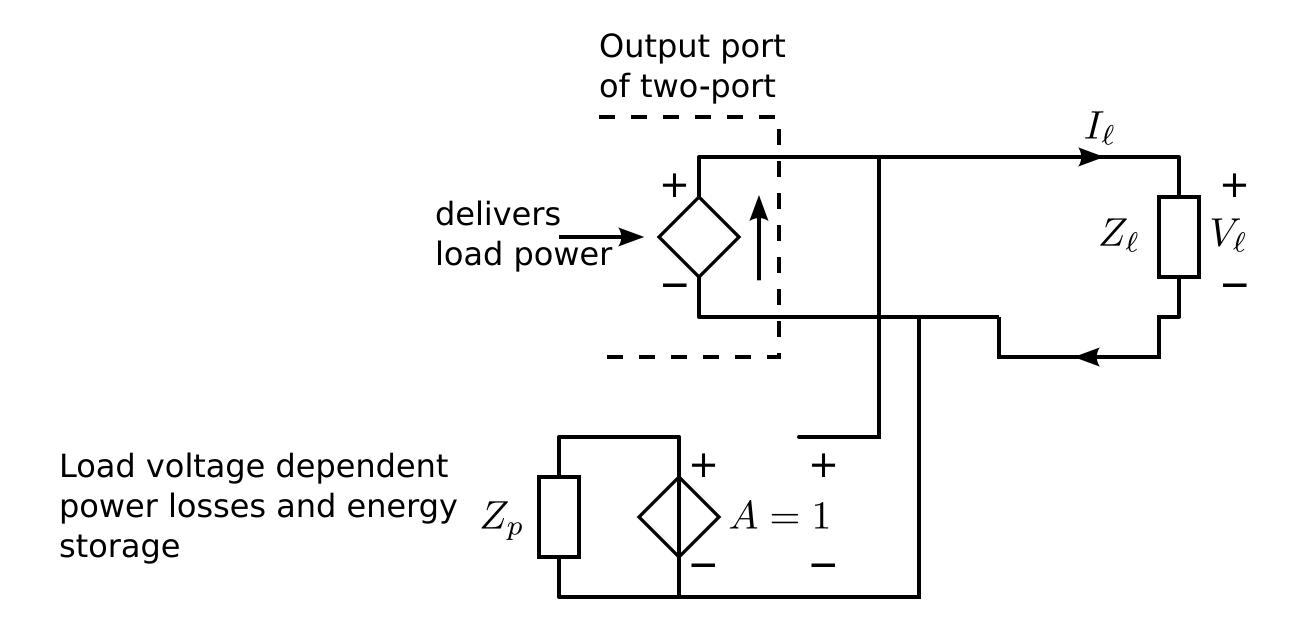
Structured Electronic Design

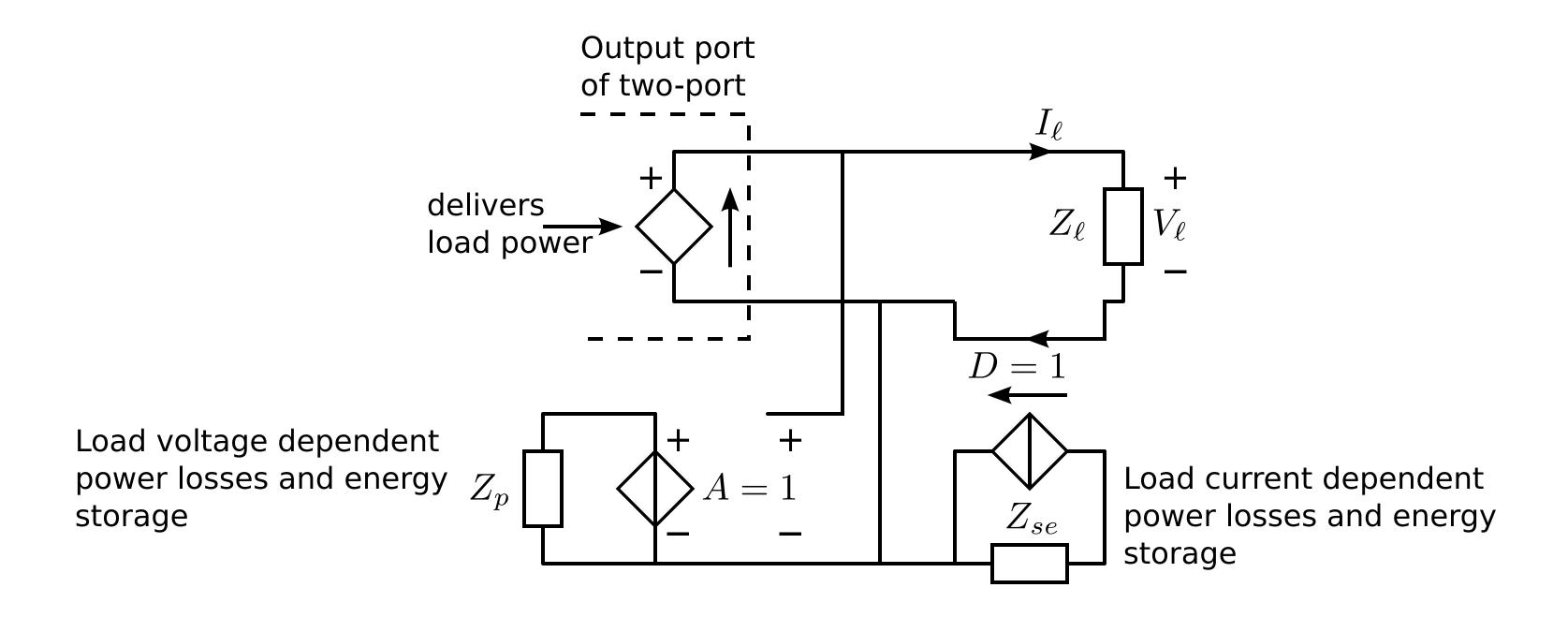
EE3C11

Amplifiers: modeling of power losses and energy storage

Anton J.M. Montagne







Power efficiency: ratio of power delivered to the load and power taken from the supply

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Application of matching networks

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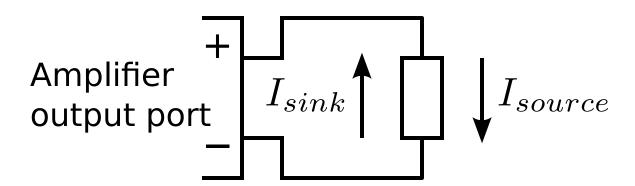
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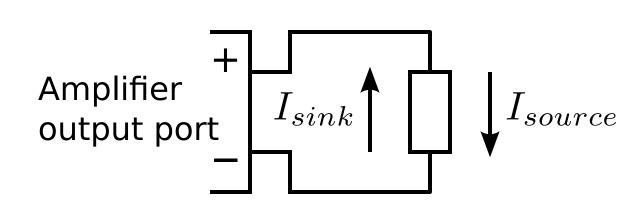
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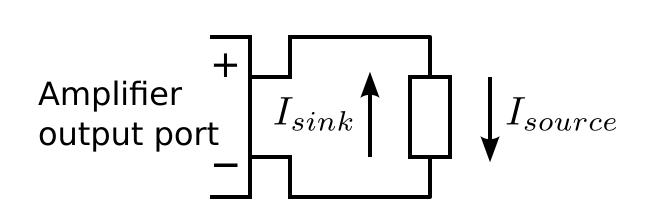
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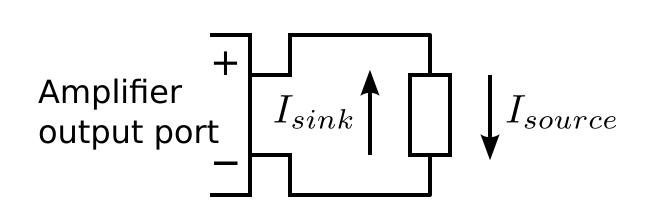


Amplifier stages constructed with devices that operate in one quadrant of the v-i plane



Amplifier stages constructed with devices that operate in one quadrant of the v-i plane

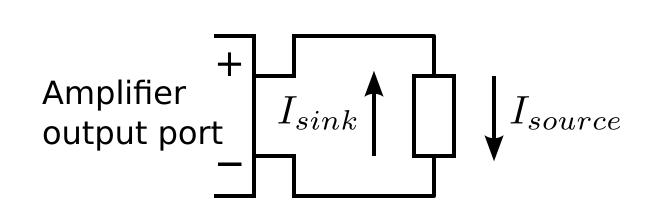
Separate output device for source and sink current



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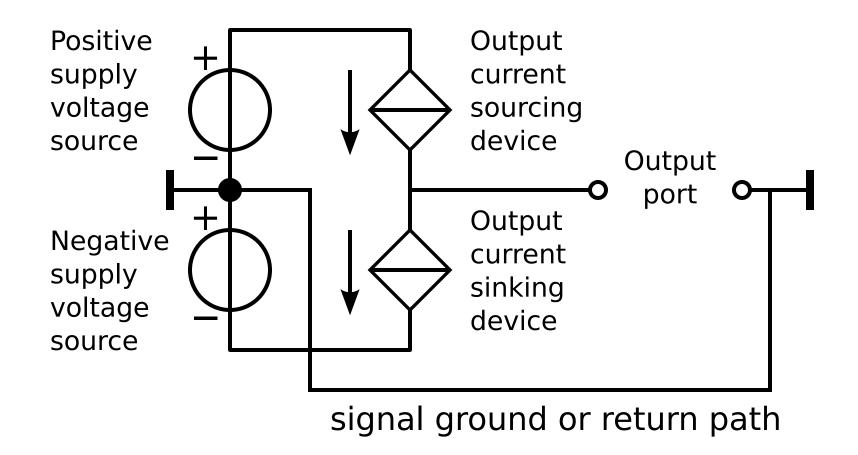
Amplifier classes relate to structure of output stage

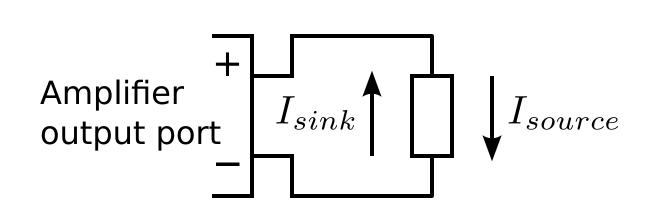


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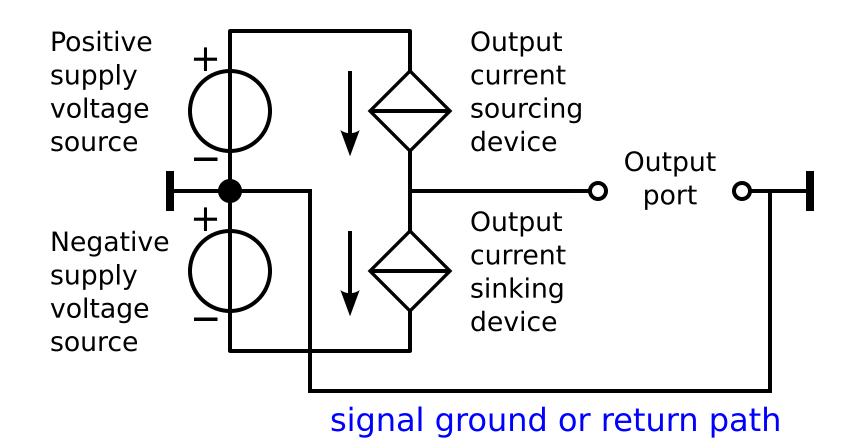


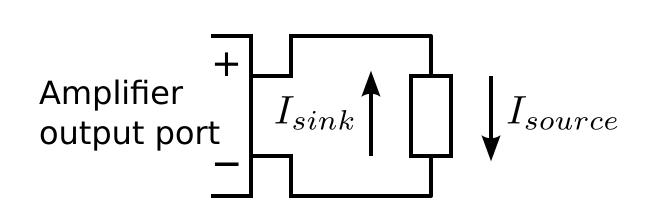


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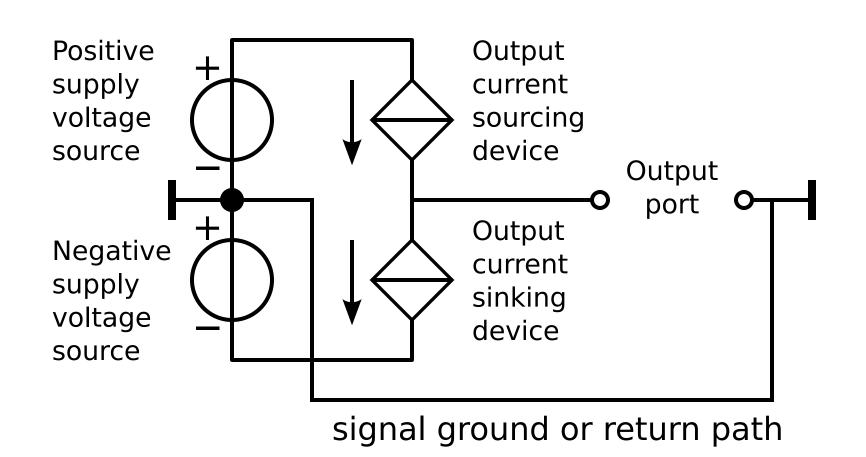




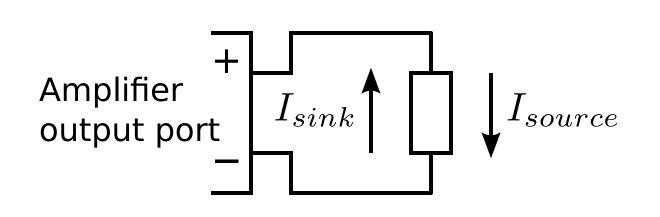
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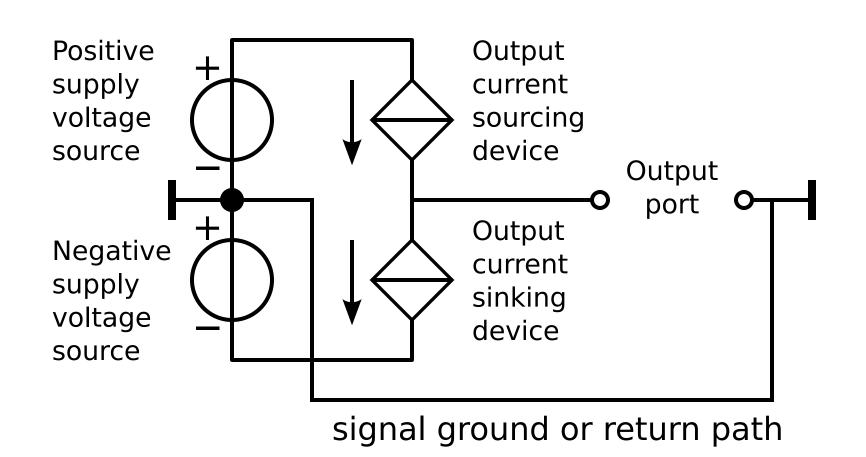
Sourcing phase:



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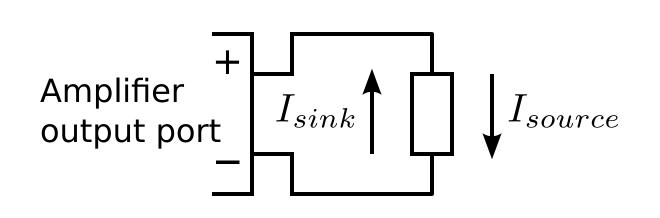
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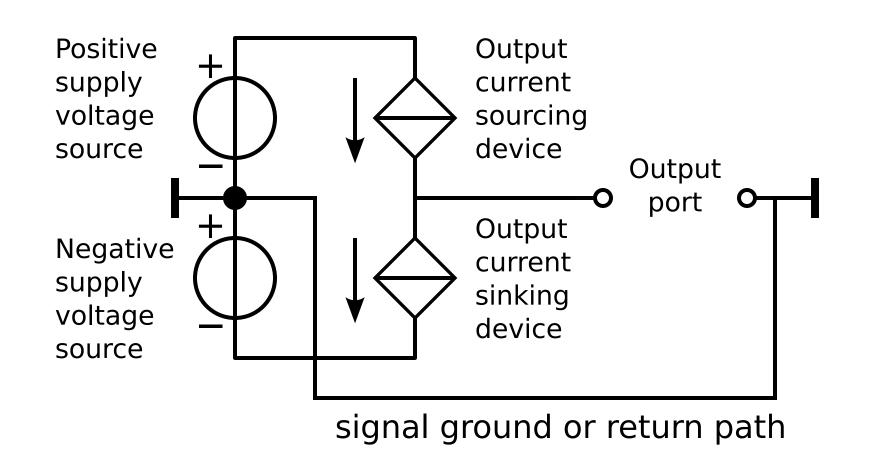
Current through sourcing device larger than current through sinking device



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Separate output device for source and sink current

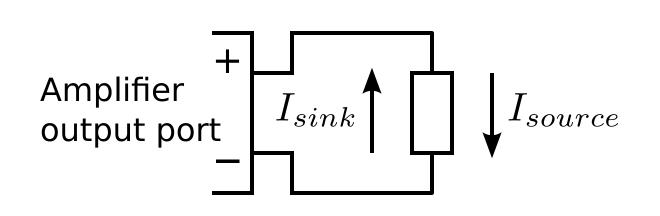
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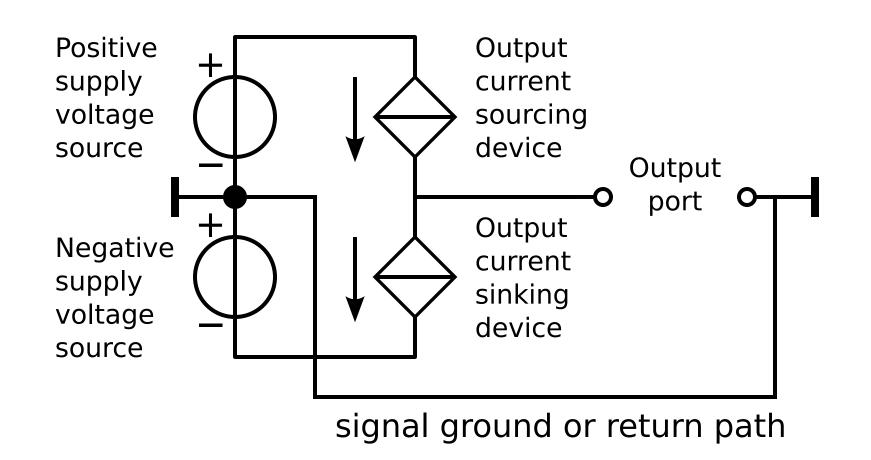
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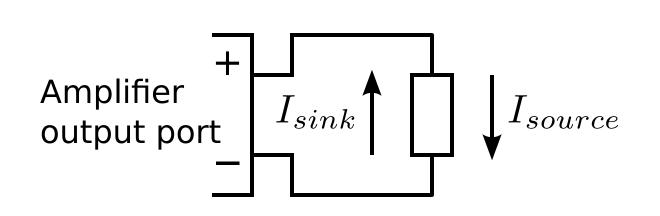


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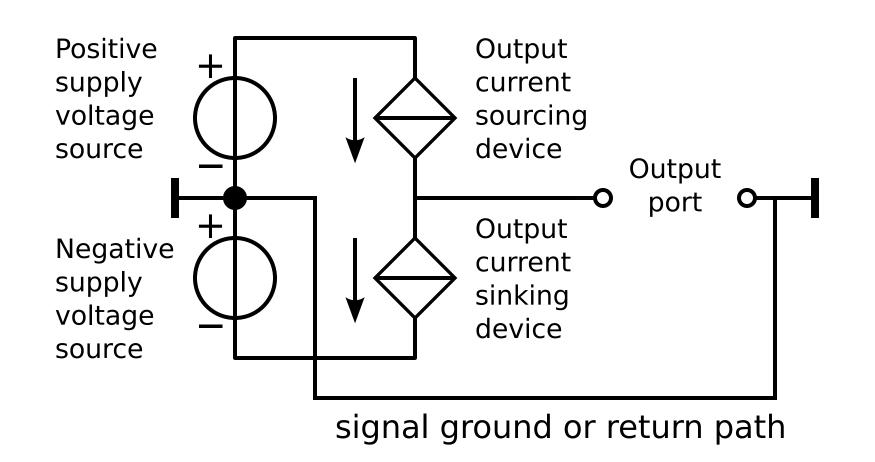
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Sourcing phase:

Current through sourcing device larger than current through sinking device

Sinking phase:

Current through sinking device larger than current through sourcing device

class A: Source and sink device both conduct during source and sink phase

class A: Source and sink device both conduct during source and sink phase

class B: Source devive conducts during source phase and sink device during sink phase

class A: Source and sink device both conduct during source and sink phase

class B: Source devive conducts during source phase and sink device during sink phase

class AB: As B but with a small overlap

class A: Source and sink device both conduct during source and sink phase

class B: Source devive conducts during source phase and sink device during sink phase

class AB: As B but with a small overlap

class C: As B but with a dead zone, or single device only

class A: Source and sink device both conduct during source and sink phase

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class D: Non resonant switching output stage

class A: Source and sink device both conduct during source and sink phase

class B: Source devive conducts during source phase and sink device during sink phase

class AB: As B but with a small overlap

class C: As B but with a dead zone, or single device only

class D: Non resonant switching output stage

class E: Resonant switching narrow-band output stage

class A: Source and sink device both conduct during source and sink phase

class B: Source devive conducts during source phase and sink device during sink phase

class AB: As B but with a small overlap

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class D: Non resonant switching output stage

class E: Resonant switching narrow-band output stage

class F: Resonant switching narrow-band output stage

class A: Source and sink device both conduct during source and sink phase

class B: Source devive conducts during source phase and sink device during sink phase

class AB: As B but with a small overlap

class C: As B but with a dead zone, or single device only

class D: Non resonant switching output stage

class E: Resonant switching narrow-band output stage

class F: Resonant switching narrow-band output stage

class G: As AB but with step-wise adaption of power supply voltage

class A: Source and sink device both conduct during source and sink phase

class B: Source devive conducts during source phase and sink device during sink phase

class AB: As B but with a small overlap

class C: As B but with a dead zone, or single device only

class D: Non resonant switching output stage

class E: Resonant switching narrow-band output stage

class F: Resonant switching narrow-band output stage

class G: As AB but with step-wise adaption of power supply voltage

class H: As AB but with continuous adaption of power supply voltage

class A: Source and sink device both conduct during source and sink phase

class B: Source devive conducts during source phase and sink device during sink phase

class AB: As B but with a small overlap

class C: As B but with a dead zone, or single device only

class D: Non resonant switching output stage

class E: Resonant switching narrow-band output stage

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